- **RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)**
- **Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards**
- **Operates With 3-V to 5.5-V V_{CC} Supply**
- **Operates Up To 250 kbit/s**
- **Two Drivers and Two Receivers**
- **Low Standby Current . . . 1 μA Typical**
- **External Capacitors . . . 4 × 0.1 μF**
- **Accepts 5-V Logic Input With 3.3-V Supply**
- **Alternative High-Speed Pin-Compatible Device (1 Mbit/s)**
  - **SNx5C3223**
- **Applications**
  - **Battery-Powered Systems, PDAs, Notebooks, Laptops, Palmtop PCs, and Hand-Held Equipment**

DB, DW, OR PW PACKAGE
(TOP VIEW)

EN	1	20	FORCEOFF
C1+	2	19	V_{CC}
V+	3	18	GND
C1−	4	17	DOUT1
C2+	5	16	RIN1
C2−	6	15	ROUT1
V−	7	14	FORCEON
DOUT2	8	13	DIN1
RIN2	9	12	DIN2
ROUT2	10	11	INVALID
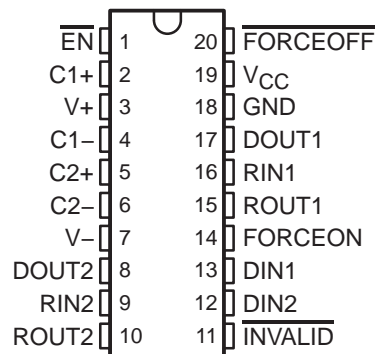
description/ordering information

The MAX3223 consists of two line drivers, two line receivers, and a dual charge-pump circuit with ±15-kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The device operates at data signaling rates up to 250 kbit/s and a maximum of 30-V/μs driver output slew rate.

ORDERING INFORMATION

T_A	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
−0°C to 70°C	SOIC (DW)	Tube of 25	MAX3223CDW	MAX3223C
		Reel of 2000	MAX3223CDWR	
	SSOP (DB)	Tube of 70	MAX3223CDB	MA3223C
		Reel of 2000	MAX3223CDBR	
	TSSOP (PW)	Tube of 70	MAX3223CPW	MA3223C
		Reel of 2000	MAX3223CPWR	
−40°C to 85°C	SOIC (DW)	Tube of 25	MAX3223IDW	MAX3223I
		Reel of 2000	MAX3223IDWR	
	SSOP (DB)	Tube of 70	MAX3223IDB	MB3223I
		Reel of 2000	MAX3223IDBR	
	TSSOP (PW)	Tube of 70	MAX3223IPW	MB3223I
		Reel of 2000	MAX3223IPWR	

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TEXAS INSTRUMENTS

description/ordering information (continued)

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense a valid RS-232 signal, the driver outputs are disabled. If FORCEOFF is set low and EN is high, both drivers and receivers are shut off, and the supply current is reduced to 1 μA. Disconnecting the serial port or turning off the peripheral drivers causes auto-powerdown to occur. Auto-powerdown can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to any receiver input. The INVALID output is used to notify the user if an RS-232 signal is present at any receiver input. INVALID is high (valid data) if any receiver input voltage is greater than 2.7 V or less than –2.7 V, or has been between –0.3 V and 0.3 V for less than 30 μs. INVALID is low (invalid data) if the receiver input voltage is between –0.3 V and 0.3 V for more than 30 μs. Refer to Figure 4 for receiver input levels.

Function Tables

EACH DRIVER

INPUTS				OUTPUT DOUT	DRIVER STATUS
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL		
X	X	L	X	Z	Powered off
L	H	H	X	H	Normal operation with auto-powerdown disabled
H	H	H	X	L	
L	L	H	Yes	H	Normal operation with auto-powerdown enabled
H	L	H	Yes	L	
L	L	H	No	Z	Powered off by auto-powerdown feature
H	L	H	No	Z	

H = high level, L = low level, X = irrelevant, Z = high impedance

EACH RECEIVER

INPUTS			OUTPUT ROUT
RIN	EN	VALID RIN RS-232 LEVEL	
L	L	X	H
H	L	X	L
X	H	X	Z
Open	L	No	H

H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

logic diagram (positive logic)
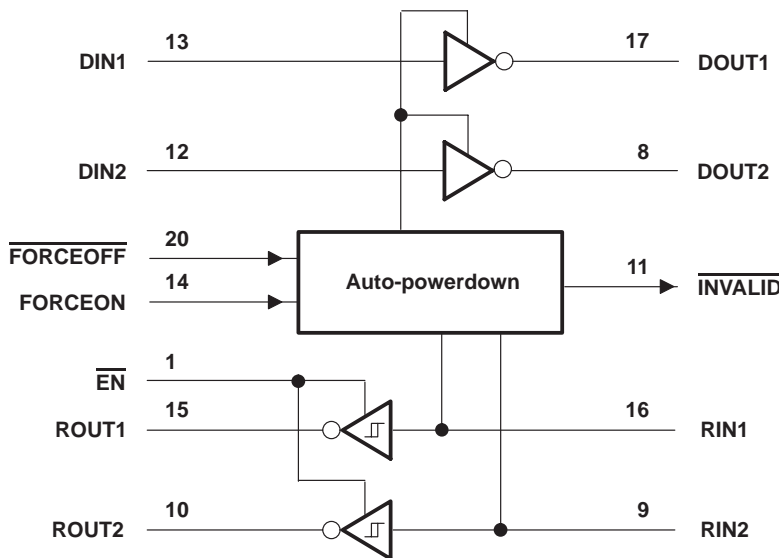
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} (see Note 1) .... −0.3 V to 6 V
Positive output supply voltage range, V+ (see Note 1) .... −0.3 V to 7 V
Negative output supply voltage range, V− (see Note 1) .... 0.3 V to −7 V
Supply voltage difference, V+ – V− (see Note 1) .... 13 V
Input voltage range, V_I: Driver, FORCEOFF, FORCEON, EN .... −0.3 V to 6 V
           Receiver .... −25 V to 25 V
Output voltage range, V_O: Driver .... −13.2 V to 13.2 V
           Receiver, INVALID .... −0.3 V to V_{CC} + 0.3 V
Package thermal impedance, θ_{JA} (see Notes 2 and 3): DB package .... 70°C/W
                                DW package .... 58°C/W
                                PW package .... 83°C/W
Operating virtual junction temperature, T_J .... 150°C
Storage temperature range, T_{stg} .... −65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to network GND.
       2. Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J$(max) – $T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
       3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4 and Figure 6)

			MIN	NOM	MAX	UNIT
	Supply voltage	V_{CC} = 3.3 V	3	3.3	3.6	V
		V_{CC} = 5 V	4.5	5	5.5	
V_{IH}	Driver and control high-level input voltage	DIN, $\overline{EN}$, $\overline{FORCEOFF}$, FORCEON — V_{CC} = 3.3 V	2			V
		V_{CC} = 5 V	2.4			
V_{IL}	Driver and control low-level input voltage	DIN, $\overline{EN}$, $\overline{FORCEOFF}$, FORCEON			0.8	V
V_I	Driver and control input voltage	DIN, $\overline{EN}$, $\overline{FORCEOFF}$, FORCEON	0		5.5	V
	Receiver input voltage		−25		25	
T_A	Operating free-air temperature	MAX3223C	0		70	°C
		MAX3223I	−40		85	

NOTE 4:   Test conditions are C1–C4 = 0.1 µF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 µF, C2–C4 = 0.33 µF at V_{CC} = 5 V ± 0.5 V.

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

PARAMETER			TEST CONDITIONS		MIN	TYP[†]	MAX	UNIT
I_I	Input leakage current	$\overline{EN}$, $\overline{FORCEOFF}$, FORCEON				±0.01	±1	µA
I_{CC}	Supply current	Auto-powerdown disabled	V_{CC} = 3.3 V or 5 V, T_A = 25°C	No load, $\overline{FORCEOFF}$ and FORCEON at V_{CC}		0.3	1	mA
		Powered off		No load, $\overline{FORCEOFF}$ at GND		1	10	µA
		Auto-powerdown enabled		No load, $\overline{FORCEOFF}$ at V_{CC}, FORCEON at GND, All RIN are open or grounded		1	10	

† All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
NOTE 4:   Test conditions are C1–C4 = 0.1 µF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 µF, C2–C4 = 0.33 µF at V_{CC} = 5 V ± 0.5 V.

DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{OH}	High-level output voltage	DOUT at R_L = 3 kΩ to GND		5	5.4		V
V_{OL}	Low-level output voltage	DOUT at R_L = 3 kΩ to GND		–5	–5.4		V
I_{IH}	High-level input current	$V_I = V_{CC}$			±0.01	±1	μA
I_{IL}	Low-level input current	V_I at GND			±0.01	±1	μA
I_{OS}	Short-circuit output current‡	V_{CC} = 3.6 V,	V_O = 0 V		±35	±60	mA
		V_{CC} = 5.5 V,	V_O = 0 V		±35	±60	
r_o	Output resistance	V_{CC}, V+, and V– = 0 V,	$V_O = ±2$ V	300	10M		Ω
I_{off}	Output leakage current	$\overline{FORCEOFF}$ = GND	$V_O = ±12$ V, V_{CC} = 3 V to 3.6 V			±25	μA
			$V_O = ±10$ V, V_{CC} = 4.5 V to 5.5 V			±25	

† All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
‡ Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.
NOTE 4:   Test conditions are C1–C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TEST CONDITIONS		MIN	TYP†	MAX	UNIT
	Maximum data rate	C_L = 1000 pF, One DOUT switching,	R_L = 3 kΩ, See Figure 1	250			kbit/s
$t_{sk(p)}$	Pulse skew§	C_L = 150 pF to 2500 pF, See Figure 2	R_L = 3 kΩ to 7 kΩ,		100		ns
$SR_{(tr)}$	Slew rate, transition region (See Figure 1)	V_{CC} = 3.3 V, R_L = 3 kΩ to 7 kΩ	C_L = 150 pF to 1000 pF	6		30	V/μs
			C_L = 150 pF to 2500 pF	4		30	

† All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
§ Pulse skew is defined as |t_{PLH} – t_{PHL}| of each channel of the same device.
NOTE 4:   Test conditions are C1–C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP[†]	MAX	UNIT
V_{OH}	High-level output voltage	$I_{OH} = -1$ mA	V_{CC}–0.6	V_{CC}–0.1		V
V_{OL}	Low-level output voltage	$I_{OL} = 1.6$ mA			0.4	V
V_{IT+}	Positive-going input threshold voltage	$V_{CC} = 3.3$ V		1.6	2.4	V
		$V_{CC} = 5$ V		1.9	2.4	
V_{IT-}	Negative-going input threshold voltage	$V_{CC} = 3.3$ V	0.6	1.1		V
		$V_{CC} = 5$ V	0.8	1.4		
V_{hys}	Input hysteresis (V_{IT+} – V_{IT-})			0.5		V
I_{off}	Output leakage current	$\overline{EN} = V_{CC}$		±0.05	±10	µA
r_i	Input resistance	$V_I = ±3$ V to ±25 V	3	5	7	kΩ

[†] All typical values are at $V_{CC} = 3.3$ V or $V_{CC} = 5$ V, and $T_A = 25°$C.
NOTE 4: Test conditions are C1–C4 = 0.1 µF at $V_{CC} = 3.3$ V ± 0.3 V; C1 = 0.047 µF, C2–C4 = 0.33 µF at $V_{CC} = 5$ V ± 0.5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4)

	PARAMETER	TEST CONDITIONS		MIN	TYP[†]	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	$C_L = 150$ pF,	See Figure 3		150		ns
t_{PHL}	Propagation delay time, high- to low-level output	$C_L = 150$ pF,	See Figure 3		150		ns
t_{en}	Output enable time	$C_L = 150$ pF, See Figure 4	$R_L = 3$ kΩ,		200		ns
t_{dis}	Output disable time	$C_L = 150$ pF, See Figure 4	$R_L = 3$ kΩ,		200		ns
$t_{sk(p)}$	Pulse skew[‡]	See Figure 3			50		ns

[†] All typical values are at $V_{CC} = 3.3$ V or $V_{CC} = 5$ V, and $T_A = 25°$C.
[‡] Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.
NOTE 4: Test conditions are C1–C4 = 0.1 µF at $V_{CC} = 3.3$ V ± 0.3 V; C1 = 0.047 µF, C2–C4 = 0.33 µF at $V_{CC} = 5$ V ± 0.5 V.

AUTO-POWERDOWN SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

PARAMETER		TEST CONDITIONS		MIN	MAX	UNIT
$V_{T+(valid)}$	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	$\overline{FORCEOFF}$ = V_{CC}		2.7	V
$V_{T-(valid)}$	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	$\overline{FORCEOFF}$ = V_{CC}	−2.7		V
$V_{T(invalid)}$	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND,	$\overline{FORCEOFF}$ = V_{CC}	−0.3	0.3	V
V_{OH}	INVALID high-level output voltage	I_{OH} = −1 mA, $\overline{FORCEOFF}$ = V_{CC}	FORCEON = GND,	V_{CC}−0.6		V
V_{OL}	INVALID low-level output voltage	I_{OL} = 1.6 mA, $\overline{FORCEOFF}$ = V_{CC}	FORCEON = GND,		0.4	V

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

PARAMETER		TYP†	UNIT
t_{valid}	Propagation delay time, low- to high-level output	1	µs
$t_{invalid}$	Propagation delay time, high- to low-level output	30	µs
t_{en}	Supply enable time	100	µs

† All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION
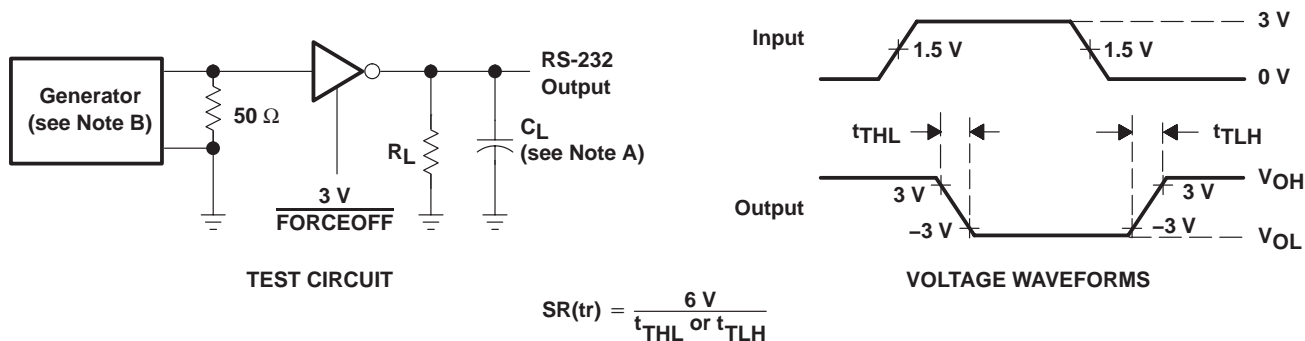
TEST CIRCUIT

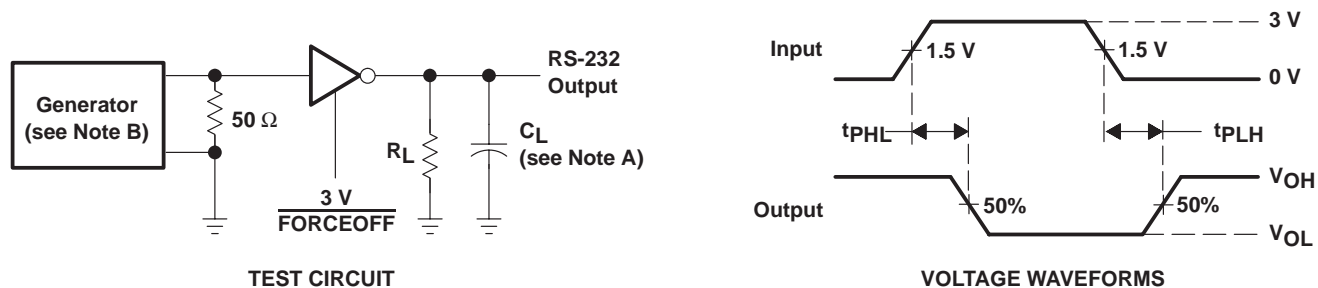**VOLTAGE WAVEFORMS**

$$SR(tr) = \frac{6\ V}{t_{THL}\ or\ t_{TLH}}$$

NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_O = 50 Ω, 50% duty cycle, t_r ≤ 10 ns, t_f ≤ 10 ns.

Figure 1. Driver Slew Rate

PARAMETER MEASUREMENT INFORMATION

TEST CIRCUIT

VOLTAGE WAVEFORMS
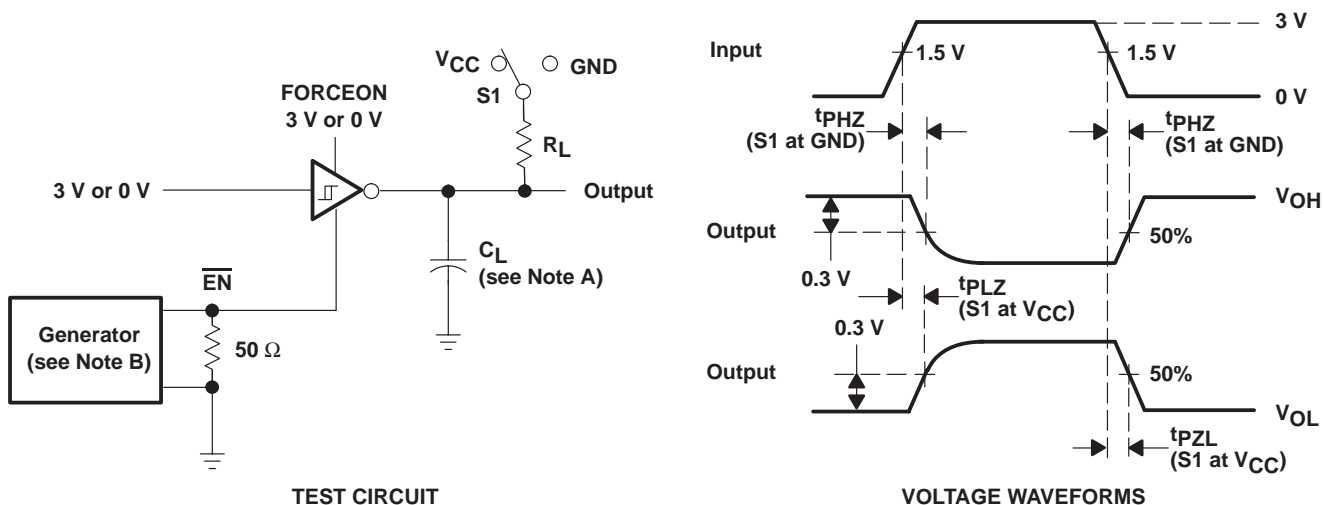
NOTES: A. C_L includes probe and jig capacitance.
          B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_O = 50 Ω, 50% duty cycle, $t_r \leq$ 10 ns, $t_f \leq$ 10 ns.

Figure 2. Driver Pulse Skew
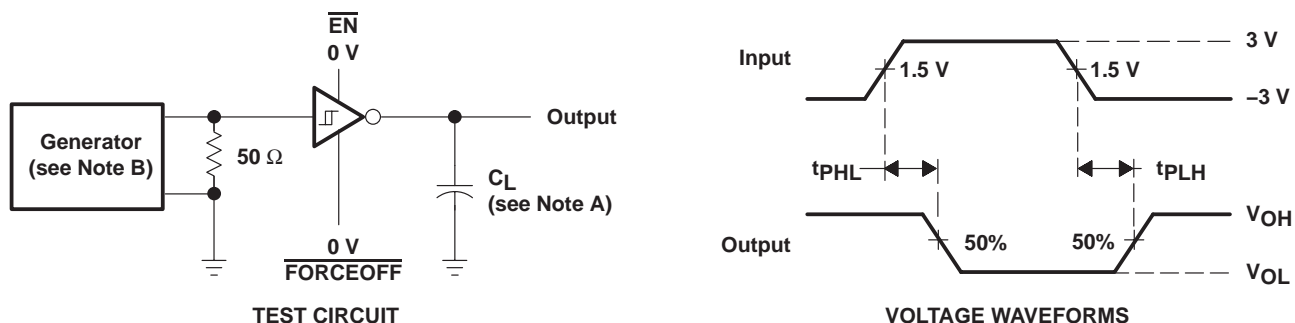
TEST CIRCUIT

VOLTAGE WAVEFORMS

NOTES: A. C_L includes probe and jig capacitance.
          B. The pulse generator has the following characteristics: Z_O = 50 Ω, 50% duty cycle, $t_r \leq$ 10 ns, $t_f \leq$ 10 ns.

Figure 3. Receiver Propagation Delay Times

TEST CIRCUIT

VOLTAGE WAVEFORMS

NOTES: A. C_L includes probe and jig capacitance.
          B. The pulse generator has the following characteristics: Z_O = 50 Ω, 50% duty cycle, $t_r \leq$ 10 ns, $t_f \leq$ 10 ns.
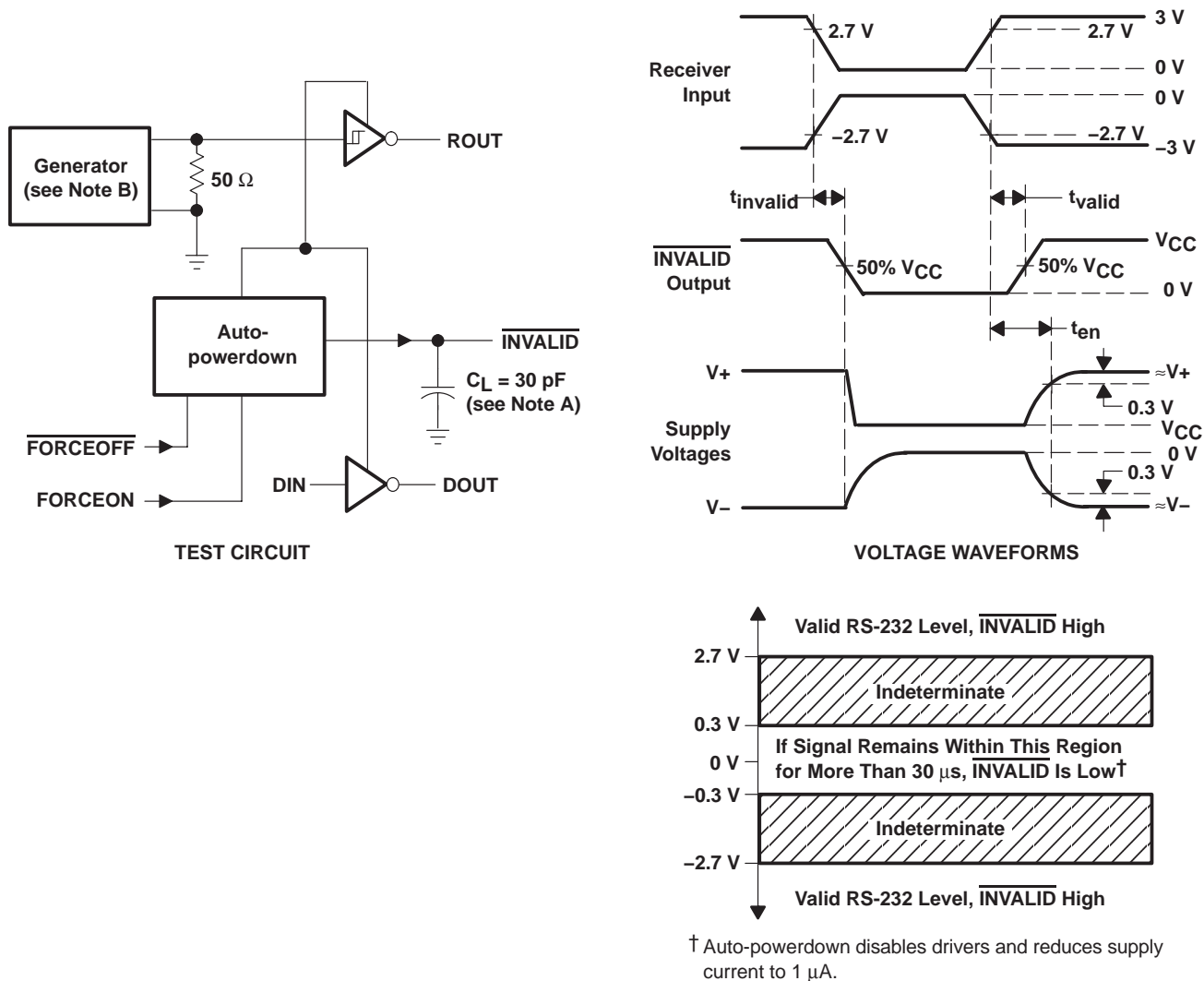
Figure 4. Receiver Enable and Disable Times

TEXAS INSTRUMENTS

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PARAMETER MEASUREMENT INFORMATION

TEST CIRCUIT

VOLTAGE WAVEFORMS

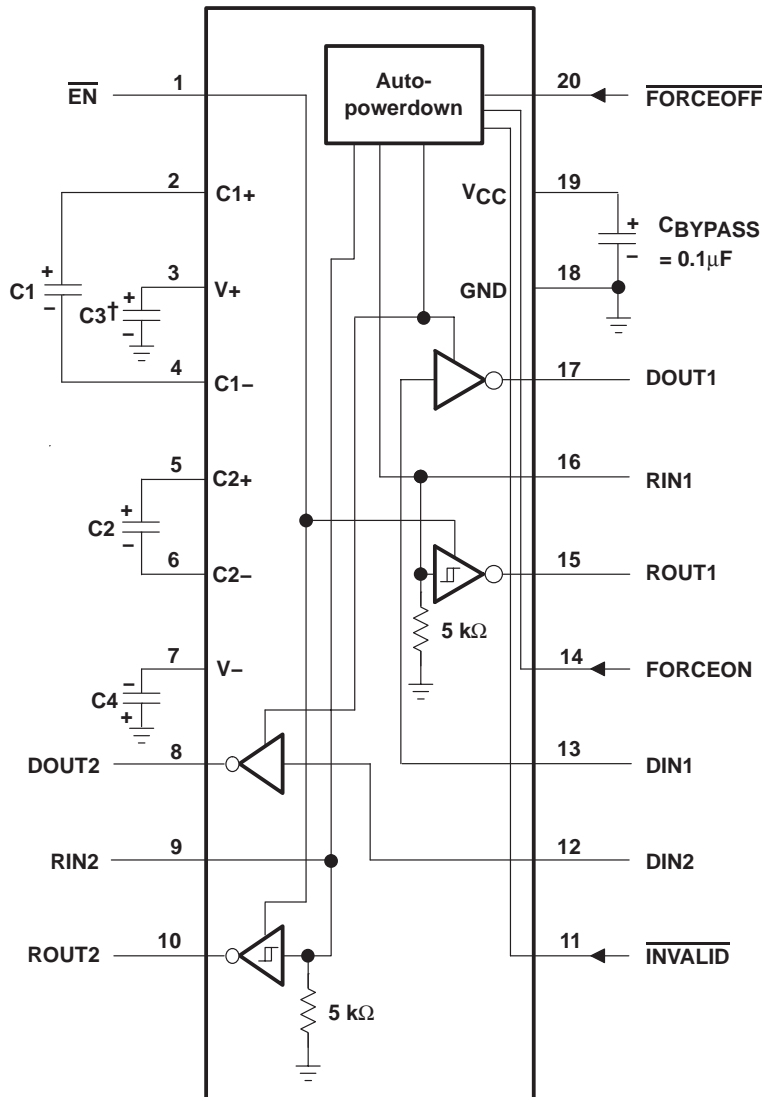† Auto-powerdown disables drivers and reduces supply
current to 1 μA.

NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: PRR = 5 kbit/s, Z_O = 50 Ω, 50% duty cycle, $t_r \leq$ 10 ns, $t_f \leq$ 10 ns.

Figure 5. INVALID Propagation Delay Times and Supply Enabling Time

APPLICATION INFORMATION

† C3 can be connected to V_{CC} or GND.

NOTES: A. Resistor values shown are nominal.
   B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

V_{CC} vs CAPACITOR VALUES

V_{CC}	C1	C2, C3, C4
3.3 V ± 0.3 V	0.1 μF	0.1 μF
5 V ± 0.5 V	0.047 μF	0.33 μF
3 V to 5.5 V	0.1 μF	0.47 μF

Figure 6. Typical Operating Circuit and Capacitor Values

TEXAS INSTRUMENTS

POST OFFICE BOX 655303 ● DALLAS, TEXAS 75265

TEXAS INSTRUMENTS

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
MAX3223CDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3223C	Samples
MAX3223CDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3223C	Samples
MAX3223CDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3223C	Samples
MAX3223CDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3223C	Samples
MAX3223CDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3223C	Samples
MAX3223CPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3223C	Samples
MAX3223CPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3223C	Samples
MAX3223IDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3223I	Samples
MAX3223IDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3223I	Samples
MAX3223IDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX3223I	Samples
MAX3223IDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX3223I	Samples
MAX3223IPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3223I	Samples
MAX3223IPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3223I	Samples
MAX3223IPWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3223I	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF MAX3223 :

• Enhanced Product: MAX3223-EP

NOTE: Qualified Version Definitions:

 • Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
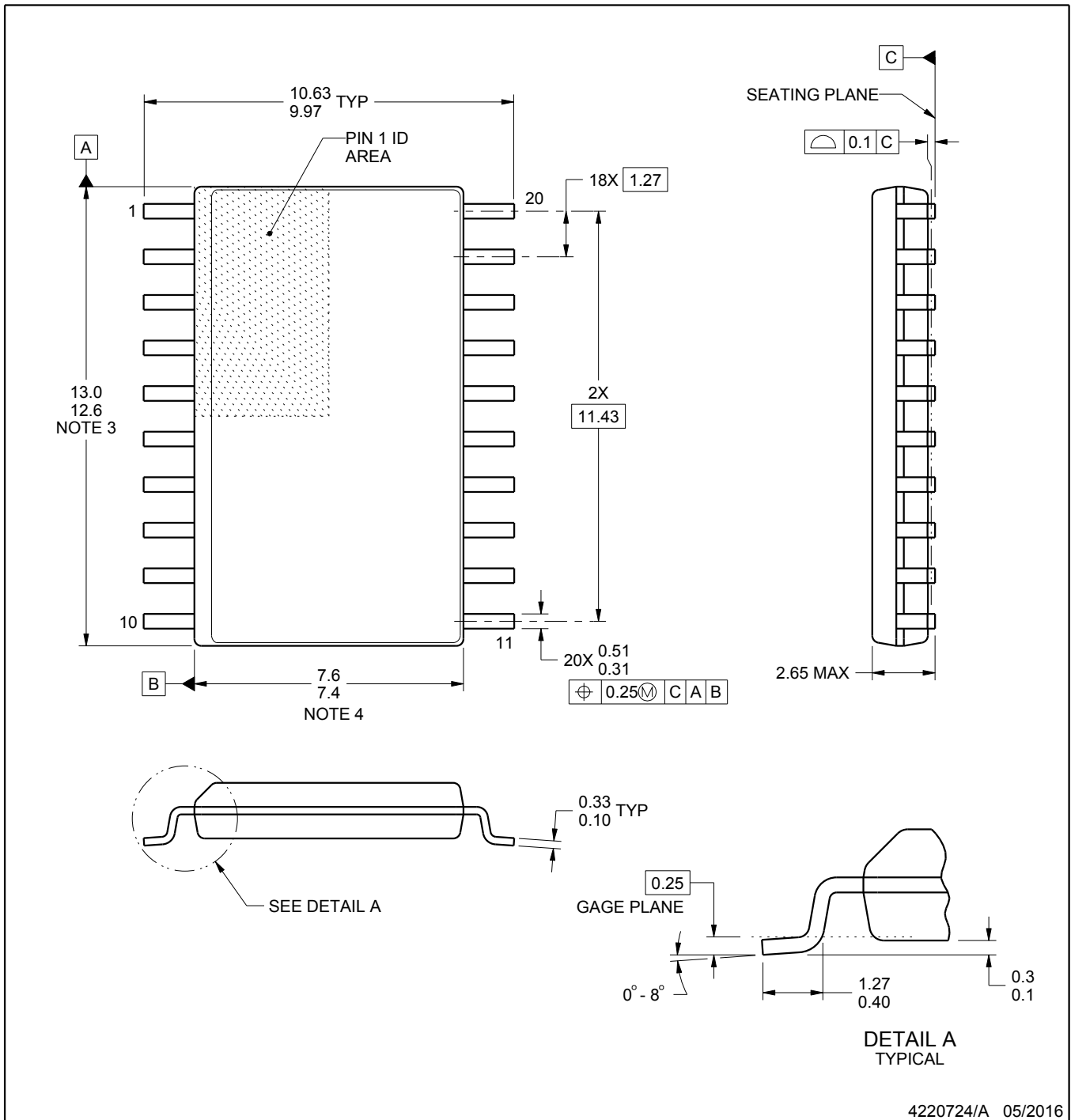

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX3223CDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
MAX3223CDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
MAX3223IDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
MAX3223IDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
MAX3223IPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX3223CDBR	SSOP	DB	20	2000	367.0	367.0	38.0
MAX3223CDWR	SOIC	DW	20	2000	367.0	367.0	45.0
MAX3223IDBR	SSOP	DB	20	2000	367.0	367.0	38.0
MAX3223IDWR	SOIC	DW	20	2000	367.0	367.0	45.0
MAX3223IPWR	TSSOP	PW	20	2000	367.0	367.0	38.0

10.63 / 9.97 TYP

A

PIN 1 ID
AREA

1

18X 1.27

20

13.0
12.6
NOTE 3

2X
11.43

10

11

B

7.6
7.4
NOTE 4

20X 0.51 / 0.31

⊕ 0.25 Ⓜ C A B

C

SEATING PLANE

�-⌐ 0.1 C

2.65 MAX

SEE DETAIL A

0.33 / 0.10 TYP

0.25
GAGE PLANE

0° - 8°

1.27
0.40

0.3
0.1

DETAIL A
TYPICAL

4220724/A   05/2016

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

20X (2)

SYMM

1

20

20X (0.6)

18X (1.27)

SYMM

(R0.05)
TYP

10

11

(9.3)

LAND PATTERN EXAMPLE
SCALE:6X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

0.07 MAX
ALL AROUND

0.07 MIN
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4220724/A   05/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

20X (2)

1

20X (0.6)

18X (1.27)

SYMM

SYMM

20

10

11

(9.3)

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

4220724/A   05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

8.2 / 7.4 TYP

A

PIN 1 INDEX AREA

1

18X 0.65

20

2X
5.85

7.5
6.9
NOTE 3

10

11

20X 0.38 / 0.22

⊕ 0.1 Ⓜ C A B

B

5.6
5.0
NOTE 4

C

0.1 C

SEATING PLANE

SEE DETAIL A

(0.15) TYP

GAGE PLANE

0.25

0° -8°

0.95
0.55

2 MAX

0.05 MIN

DETAIL A
TYPICAL
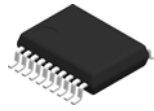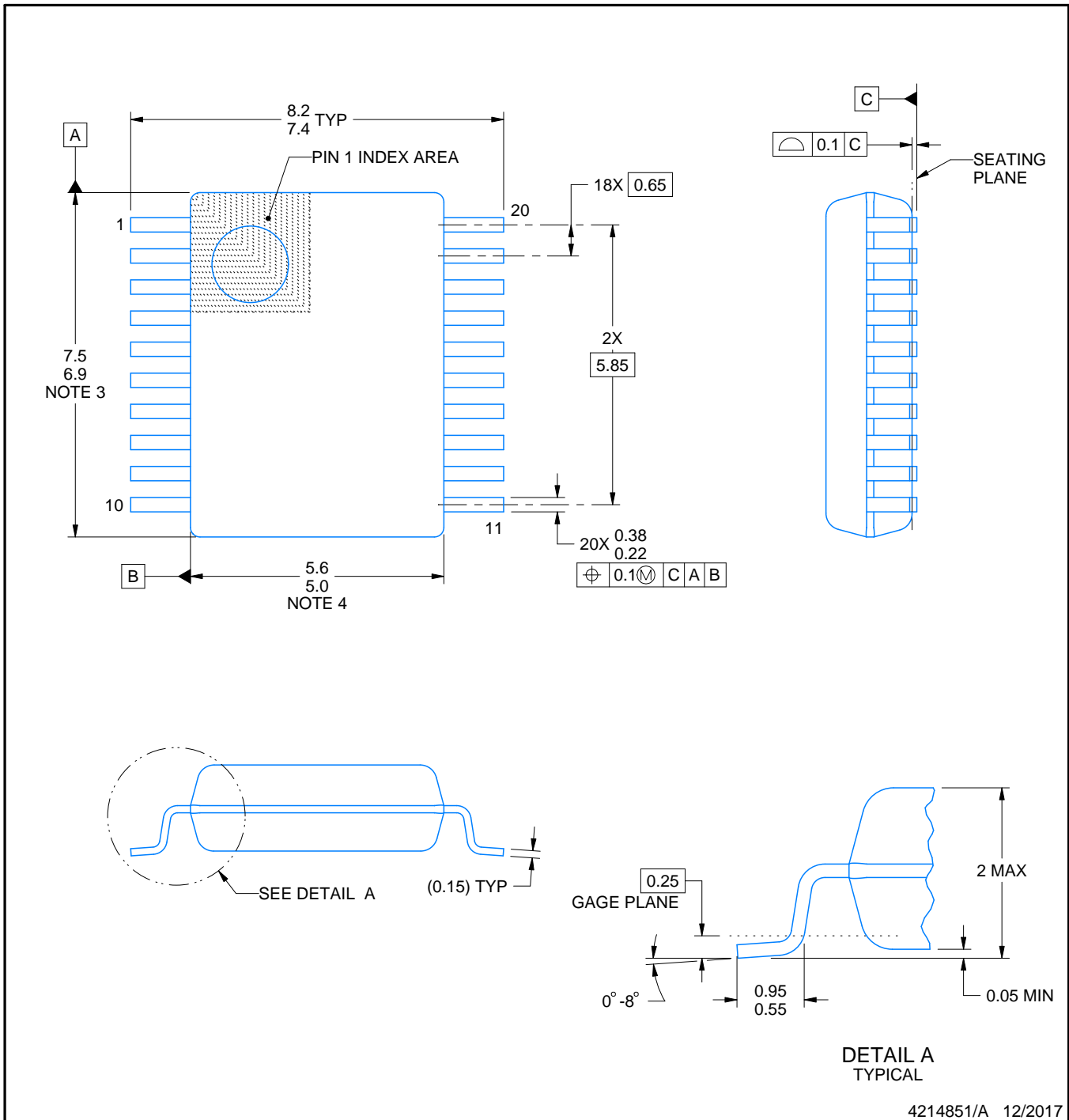
4214851/A   12/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-150.

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20X (1.85)

SYMM

1

20X (0.45)

(R0.05) TYP

20

18X (0.65)

SYMM

10

11

(7)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.07 MAX
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.07 MIN
ALL AROUND

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214851/A   12/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

20X (1.85)

SYMM

(R0.05) TYP

1

20X (0.45)

20

18X (0.65)

SYMM

10

11

(7)

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4214851/A   12/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PW (R−PDSO−G20)   PLASTIC SMALL OUTLINE

0,65   0,30 / 0,19   ⊕ 0,10 Ⓜ

20   11

4,50 / 4,30   6,60 / 6,20

1   10

6,60 / 6,40

Ⓒ

0,15 NOM
Gage Plane
0°−8°
0,25
0,75 / 0,50

1,20 MAX   0,15 / 0,05

Seating Plane
⌓ 0,10

4040064−5/G 02/11

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
        B. This drawing is subject to change without notice.
        Ⓒ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
        Ⓓ Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
        E. Falls within JEDEC MO−153

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PW (R−PDSO−G20) PLASTIC SMALL OUTLINE

Example Board Layout

Based on a stencil thickness
of .127mm (.005inch).

18x0,65

20x0,25

1,55

5,6

5,6

18x0,65

Example
Non Soldermask Defined Pad

Example
Solder Mask Opening
(See Note E)

0,3

1,6

Pad Geometry

0,07
All Around

4211284−5/G 08/15

NOTES: A. All linear dimensions are in millimeters.
        B. This drawing is subject to change without notice.
        C. Publication IPC−7351 is recommended for alternate design.
        D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
            contact their board assembly site for stencil design recommendations. Refer to IPC−7525 for other stencil recommendations.
        E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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